

## IR2213(S)

### HIGH AND LOW SIDE DRIVER

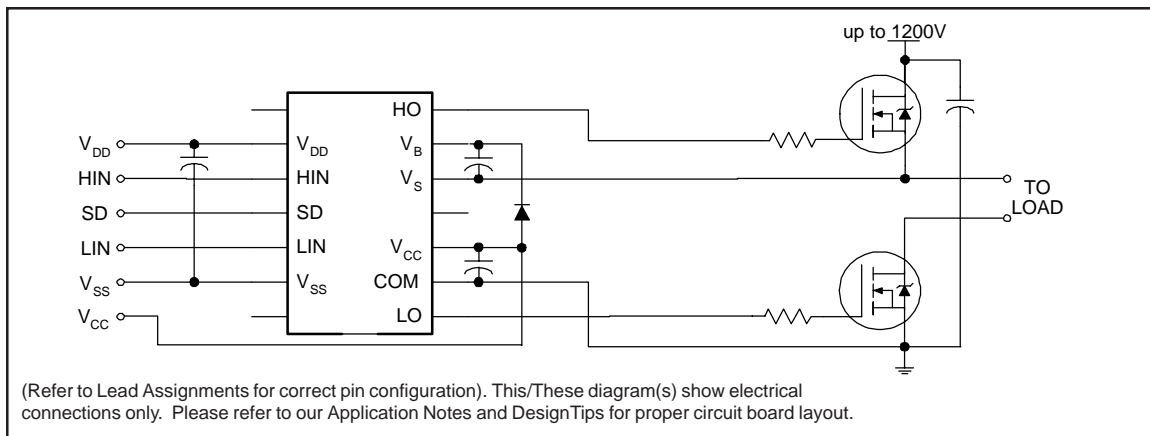
#### Features

- Floating channel designed for bootstrap operation  
Fully operational to +1200V  
Tolerant to negative transient voltage  
dV/dt immune
- Gate drive supply range from 12 to 20V
- Undervoltage lockout for both channels
- 3.3V logic compatible  
Separate logic supply range from 3.3V to 20V  
Logic and power ground  $\pm 5V$  offset
- CMOS Schmitt-triggered inputs with pull-down
- Cycle by cycle edge-triggered shutdown logic
- Matched propagation delay for both channels
- Outputs in phase with inputs

#### Description

The IR2213(S) is a high voltage, high speed power MOSFET and IGBT driver with independent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. Logic inputs are compatible with standard CMOS or LSTTL outputs, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 1200 volts.

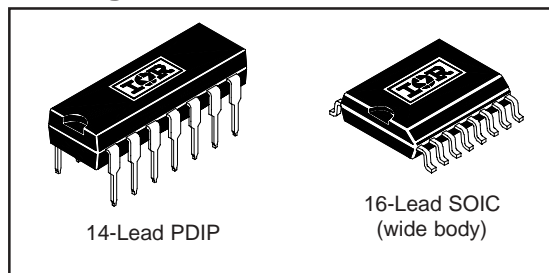
#### Typical Connection



#### Product Summary

$V_{OFFSET}$	1200V max.
$I_{O+/-}$	1.7A / 2A
$V_{OUT}$	12 - 20V
$t_{on/off} (typ.)$	280 & 225 ns
Delay Matching	30 ns

#### Packages



## Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
$V_B$	High Side Floating Supply Voltage	-0.3	1225	
$V_S$	High Side Floating Supply Offset Voltage	$V_B - 25$	$V_B + 0.3$	V
$V_{HO}$	High Side Floating Output Voltage	$V_S - 0.3$	$V_B + 0.3$	
$V_{CC}$	Low Side Fixed Supply Voltage	-0.3	25	
$V_{LO}$	Low Side Output Voltage	-0.3	$V_{CC} + 0.3$	
$V_{DD}$	Logic Supply Voltage	-0.3	$V_{SS} + 25$	
$V_{SS}$	Logic Supply Offset Voltage	$V_{CC} - 25$	$V_{CC} + 0.3$	
$V_{IN}$	Logic Input Voltage (HIN, LIN & SD)	$V_{SS} - 0.3$	$V_{DD} + 0.3$	
$dV_S/dt$	Allowable Offset Supply Voltage Transient (Figure 2)	—	50	V/ns
$P_D$	Package Power Dissipation @ $T_A \leq +25^\circ\text{C}$	(14 Lead PDIP)	1.6	W
		(16 Lead SOIC)	1.25	
$R_{THJA}$	Thermal Resistance, Junction to Ambient	(14 Lead PDIP)	75	$^\circ\text{C/W}$
		(16 Lead SOIC)	100	
$T_J$	Junction Temperature	—	125	$^\circ\text{C}$
$T_S$	Storage Temperature	-55	150	
$T_L$	Lead Temperature (Soldering, 10 seconds)	—	300	

## Recommended Operating Conditions

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The  $V_S$  and  $V_{SS}$  offset ratings are tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
$V_B$	High Side Floating Supply Absolute Voltage	$V_S + 12$	$V_S + 20$	V
$V_S$	High Side Floating Supply Offset Voltage	Note 1	1200	
$V_{HO}$	High Side Floating Output Voltage	$V_S$	$V_B$	
$V_{CC}$	Low Side Fixed Supply Voltage	12	20	
$V_{LO}$	Low Side Output Voltage	0	$V_{CC}$	
$V_{DD}$	Logic Supply Voltage	$V_{SS} + 3$	$V_{SS} + 20$	
$V_{SS}$	Logic Supply Offset Voltage	-5 (Note 2)	5	
$V_{IN}$	Logic Input Voltage (HIN, LIN & SD)	$V_{SS}$	$V_{DD}$	

Note 1: Logic operational for  $V_S$  of -5 to +1200V. Logic state held for  $V_S$  of -5V to  $-V_{BS}$ . (Please refer to the Design Tip DT97-3 for more details).

Note 2: When  $V_{DD} < 5V$ , the minimum  $V_{SS}$  offset is limited to  $-V_{DD}$

## Dynamic Electrical Characteristics

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ,  $V_{DD}$ ) = 15V,  $C_L$  = 1000 pF,  $T_A$  = 25°C and  $V_{SS}$  = COM unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in Figure 3.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$t_{on}$	Turn-On Propagation Delay	—	280	—	ns	$V_S = 0V$
$t_{off}$	Turn-Off Propagation Delay	—	225	—		$V_S = 1200V$
$t_{sd}$	Shutdown Propagation Delay	—	230	—		$V_S = 1200V$
$t_r$	Turn-On Rise Time	—	25	—		
$t_f$	Turn-Off Fall Time	—	17	—		
MT	Delay Matching, HS & LS Turn-On/Off	—	—	30		Figure 5

## Static Electrical Characteristics

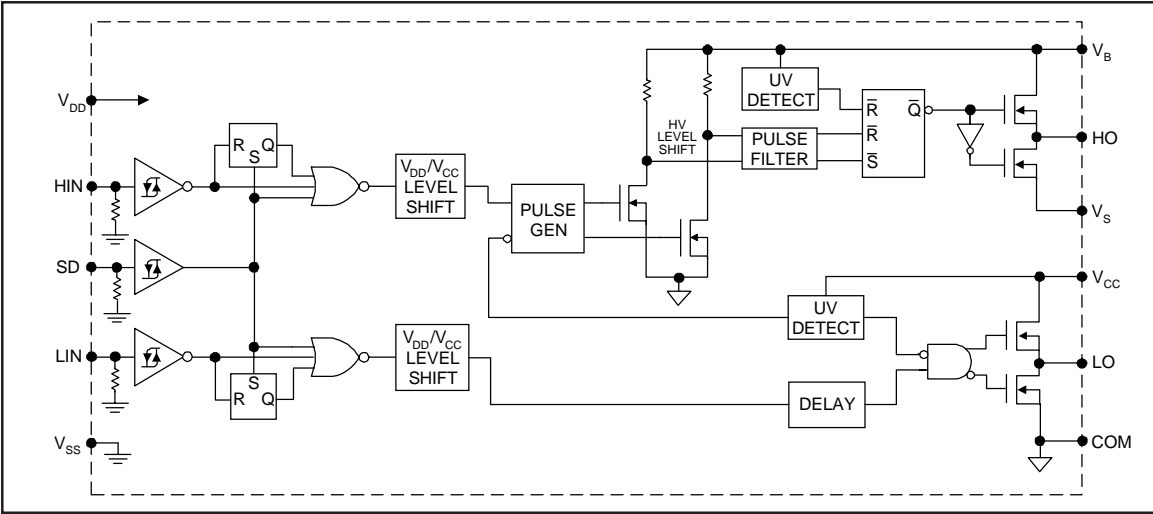
$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ,  $V_{DD}$ ) = 15V,  $T_A$  = 25°C and  $V_{SS}$  = COM unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to  $V_{SS}$  and are applicable to all three logic input leads: HIN, LIN and SD. The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$V_{IH}$	Logic "1" Input Voltage	9.5	—	—	V	
$V_{IL}$	Logic "0" Input Voltage	—	—	6.0		
$V_{OH}$	High Level Output Voltage, $V_{BIAS} - V_O$	—	—	1.2		$I_O = 0A$
$V_{OL}$	Low Level Output Voltage, $V_O$	—	—	0.1		$I_O = 0A$
$I_{LK}$	Offset Supply Leakage Current	—	—	50	$\mu A$	$V_B = V_S = 1200V$
$I_{QBS}$	Quiescent $V_{BS}$ Supply Current	—	125	230		$V_{IN} = 0V$ or $V_{DD}$
$I_{QCC}$	Quiescent $V_{CC}$ Supply Current	—	180	340		$V_{IN} = 0V$ or $V_{DD}$
$I_{QDD}$	Quiescent $V_{DD}$ Supply Current	—	15	30		$V_{IN} = 0V$ or $V_{DD}$
$I_{IN+}$	Logic "1" Input Bias Current	—	20	40		$V_{IN} = V_{DD}$
$I_{IN-}$	Logic "0" Input Bias Current	—	—	1.0		$V_{IN} = 0V$
$V_{BSUV+}$	$V_{BS}$ Supply Undervoltage Positive Going Threshold	8.7	10.2	11.7	V	
$V_{BSUV-}$	$V_{BS}$ Supply Undervoltage Negative Going Threshold	7.9	9.3	10.7		
$V_{CCUV+}$	$V_{CC}$ Supply Undervoltage Positive Going Threshold	8.7	10.2	11.7		
$V_{CCUV-}$	$V_{CC}$ Supply Undervoltage Negative Going Threshold	7.9	9.3	10.7		
$I_{O+}$	Output High Short Circuit Pulsed Current	1.7	2.0	—	A	$V_O = 0V$ , $V_{IN} = V_{DD}$ $PW \leq 10 \mu s$
$I_{O-}$	Output Low Short Circuit Pulsed Current	2.0	2.5	—		$V_O = 15V$ , $V_{IN} = 0V$ $PW \leq 10 \mu s$

# IR2213(S)

International  
IR Rectifier

## Functional Block Diagram



## Lead Definitions

Symbol	Description
VDD	Logic supply
HIN	Logic input for high side gate driver output (HO), in phase
SD	Logic input for shutdown
LIN	Logic input for low side gate driver output (LO), in phase
VSS	Logic ground
V <sub>B</sub>	High side floating supply
HO	High side gate drive output
V <sub>S</sub>	High side floating supply return
VCC	Low side supply
LO	Low side gate drive output
COM	Low side return

## Lead Assignments

<b>IR2213</b>	<b>IR2213S</b>
<b>Part Number</b>	

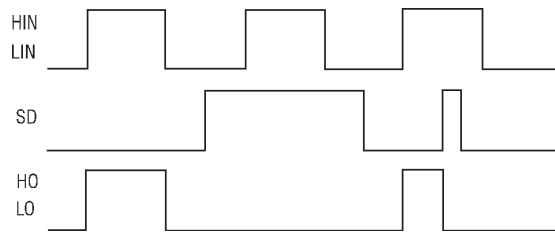


Figure 1. Input/Output Timing Diagram

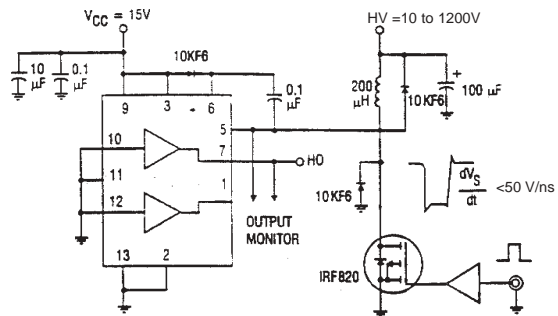


Figure 2. Floating Supply Voltage Transient Test Circuit

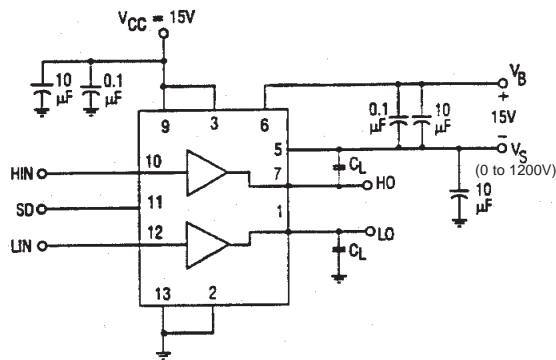


Figure 3. Switching Time Test Circuit

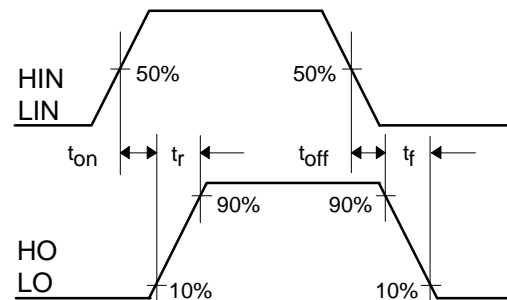


Figure 4. Switching Time Waveform Definition

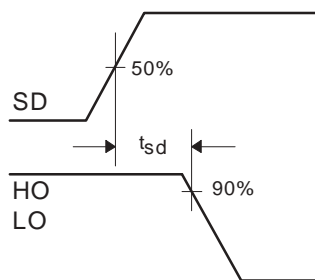


Figure 5. Shutdown Waveform Definitions

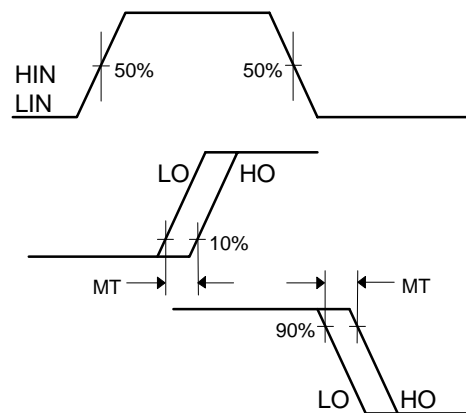


Figure 6. Delay Matching Waveform Definitions

# IR2213(S)

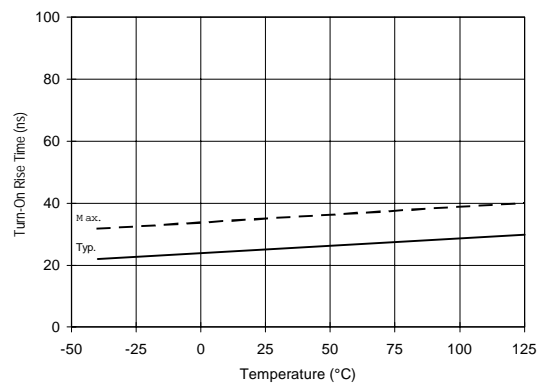


Figure 10A. Turn-On Rise Time vs. Temperature

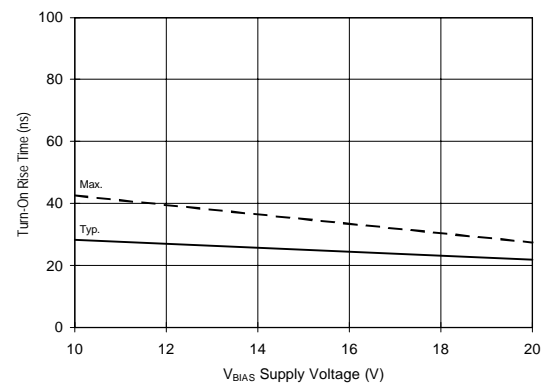


Figure 10B. Turn-On Rise Time vs. Voltage

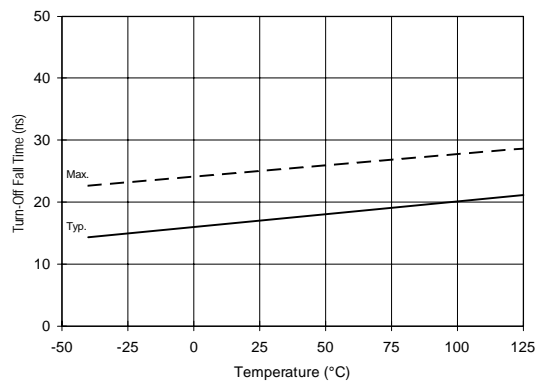


Figure 11A. Turn-Off Fall Time vs. Temperature

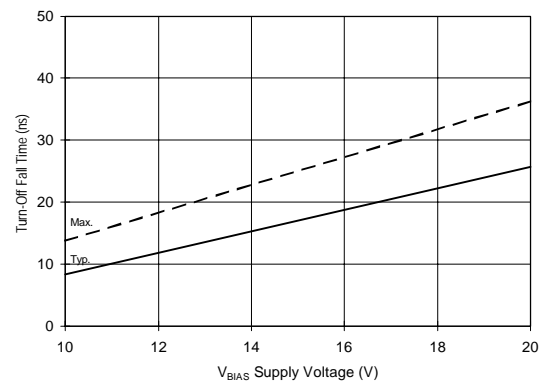


Figure 11B. Turn-Off Fall Time vs. Voltage

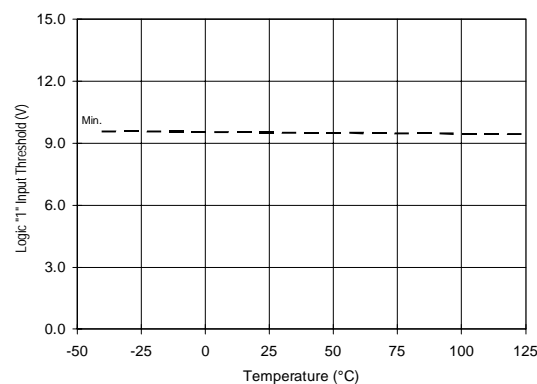


Figure 12A. Logic "1" Input Threshold vs. Temperature

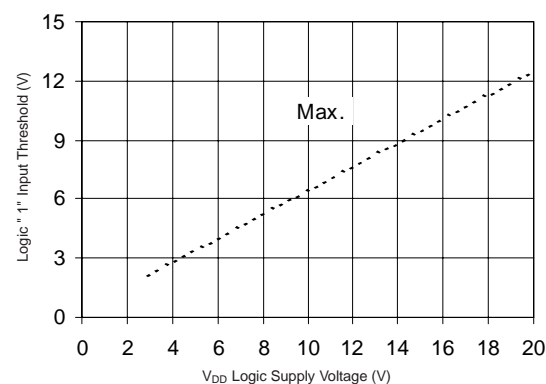


Figure 12B. Logic "1" Input Threshold vs. Voltage

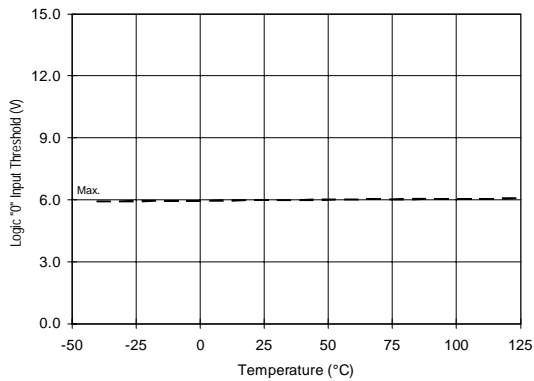


Figure 13A. Logic "0" Input Threshold vs. Temperature

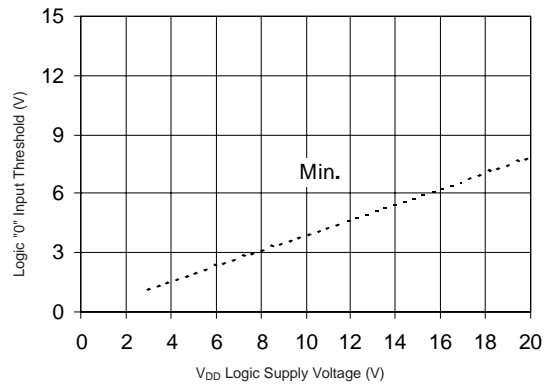


Figure 13B. Logic "0" Input Threshold vs. Voltage

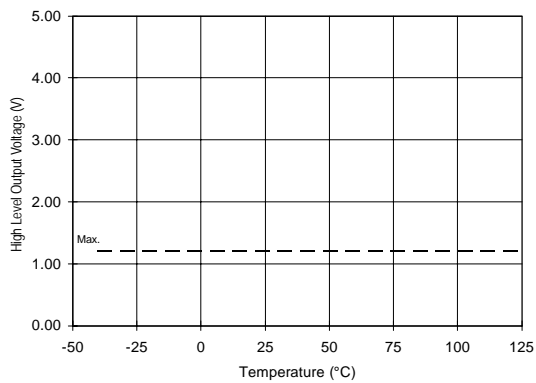


Figure 14A. High Level Output vs. Temperature

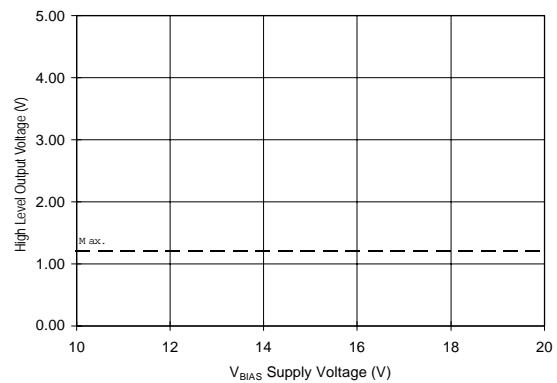


Figure 14B. High Level Output vs. Voltage

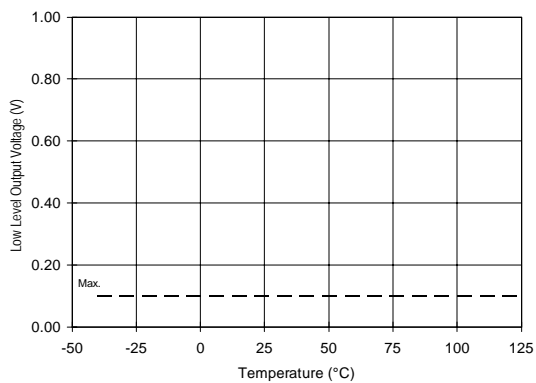


Figure 15A. Low Level Output vs. Temperature

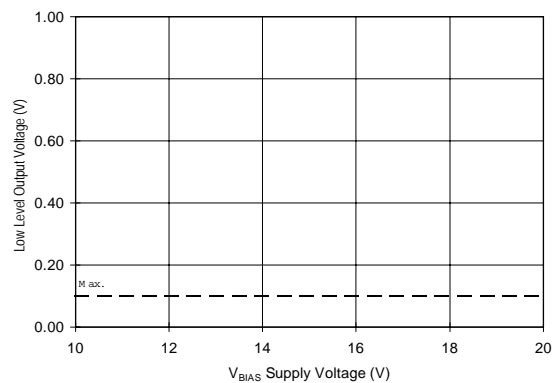
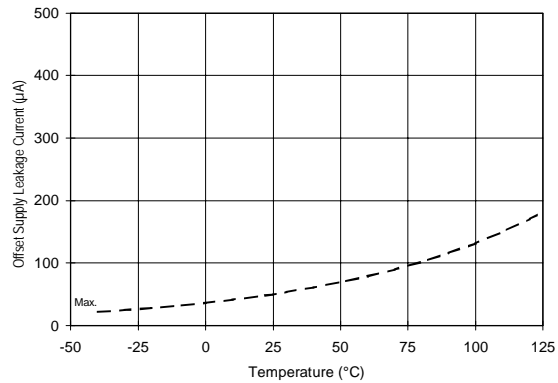
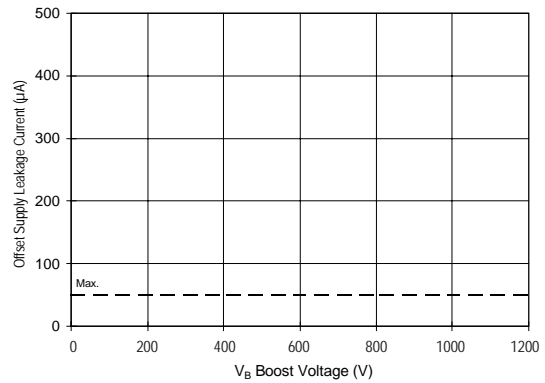


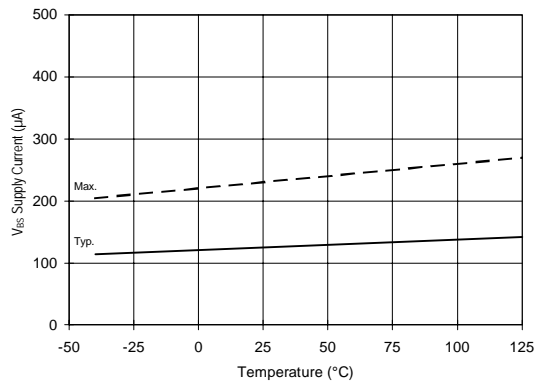
Figure 15B. Low Level Output vs. Voltage



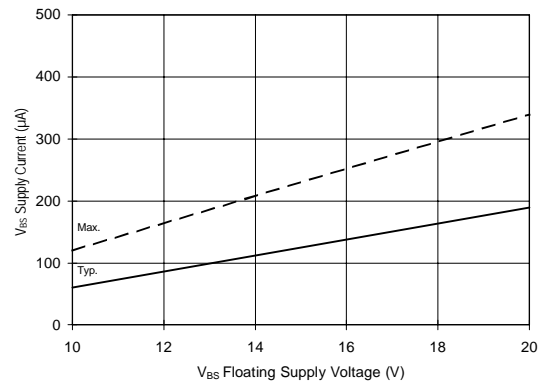
**Figure 16A. Offset Supply Current vs. Temperature**



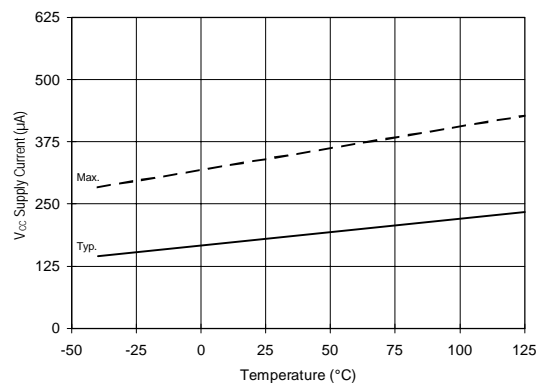
**Figure 16B. Offset Supply Current vs. Voltage**



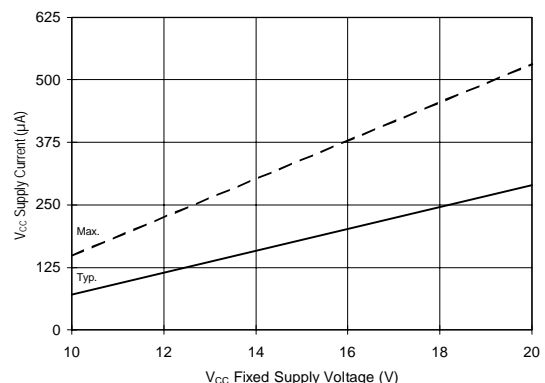
**Figure 17A. V<sub>BS</sub> Supply Current vs. Temperature**



**Figure 17B. V<sub>BS</sub> Supply Current vs. Voltage**

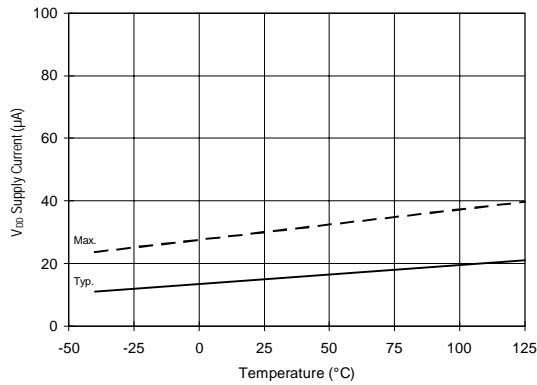


**Figure 18A. V<sub>CC</sub> Supply Current vs. Temperature**

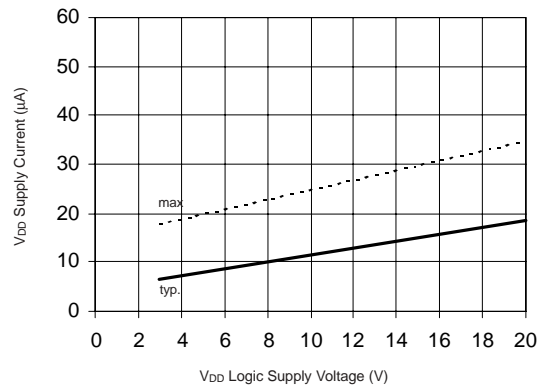


**Figure 18B. V<sub>CC</sub> Supply Current vs. Voltage**

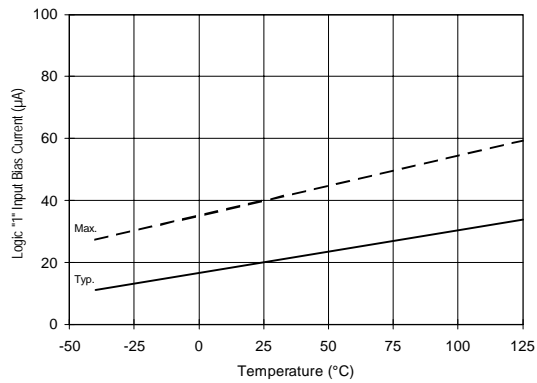




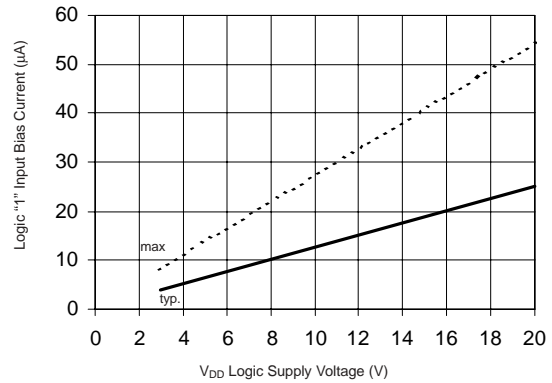
**Figure 19A. V<sub>DD</sub> Supply Current vs. Temperature**



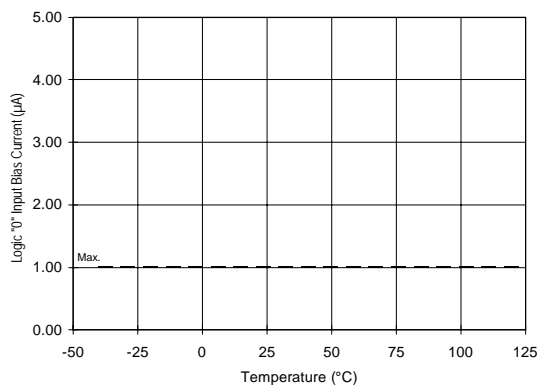
**Figure 19B. V<sub>DD</sub> Supply Current vs. V<sub>DD</sub> Voltage**



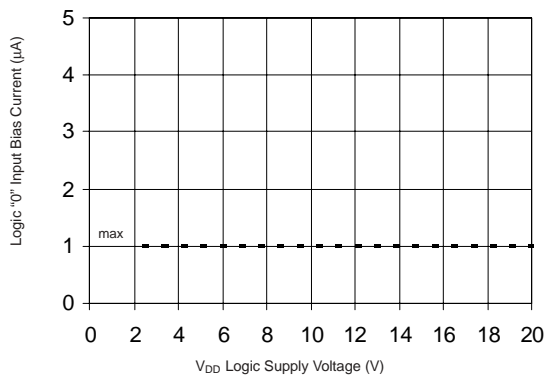
**Figure 20A. Logic "1" Input Current vs. Temperature**



**Figure 20B. Logic "1" Input Current vs. V<sub>DD</sub> Voltage**



**Figure 21A. Logic "0" Input Current vs. Temperature**



**Figure 21B. Logic "0" Input Current vs. V<sub>DD</sub> Voltage**

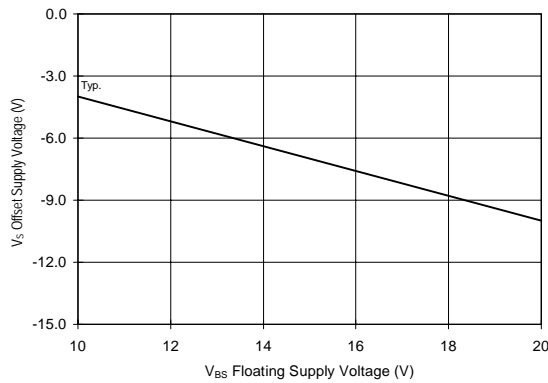


Figure 36. Maximum V<sub>S</sub> Negative Offset vs. V<sub>BS</sub> Supply Voltage

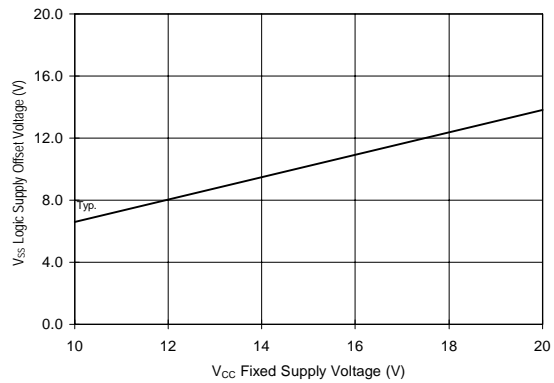


Figure 37. Maximum V<sub>SS</sub> Positive Offset vs. V<sub>CC</sub> Supply Voltage

## Case outlines

